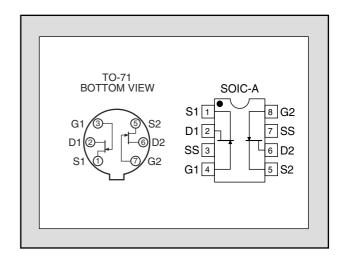


Linear Integrated Systems

FEATURES						
ULTRA LOW NOISE	en	= 0.9nV/√Hz (typ)				
TIGHT MATCHING	_{SS1-2} = 20mV max					
HIGH BREAKDOWN VOLTAGE						
HIGH GAIN	$Y_{fs} = 20 \text{mS (typ)}$					
LOW CAPACITANCE		25pF typ				
IMPROVED SECOND SOURCE REPLACEMENT FOR 2SK389						
ABSOLUTE MAXIMUM RATINGS ¹						
@ 25 °C (unless otherwise stated)						
Maximum Temperatures						
Storage Temperature	-65 to +150 °C					
Operating Junction Temperature	-55 to +135 °C					
Maximum Power Dissipation						
Continuous Power Dissipation @ +125 °C	400mW					
Maximum Currents						
Gate Forward Current	$I_{G(F)} = 10mA$					
Maximum Voltages						
Gate to Source	$V_{GSS} = 40V$					
Gate to Drain	$V_{GDS} = 40V$					

LSK389

ULTRA LOW NOISE MONOLITHIC DUAL N-CHANNEL JFET



*For equivalent single version, see LSK170 family.

MATCHING CHARACTERISTICS @ 25 °C (unless otherwise stated)

SYMBOL	CHARACTERISTIC	MIN	TYP	MAX	UNIT	CONDITIONS
$\left V_{GS1}-V_{GS2}\right $	Differential Gate to Source Cutoff Voltage			20	mV	V _{DS} = 10V, I _D = 1mA
IDSS1 IDSS2	Gate to Source Saturation Current Ratio	0.9			-	V _{DS} = 10V, V _{GS} = 0V

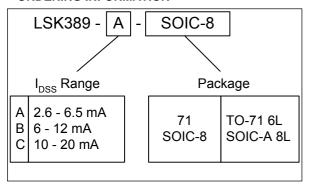
ELECTRICAL CHARACTERISTICS @ 25 °C (unless otherwise stated)

SYMBOL	CHARACTERISTIC		MIN	TYP	MAX	UNITS	CONDITIONS
BV _{GSS}	Gate to Source Breakdown Voltage Gate to Source Pinch-off Voltage		40			>	$V_{DS} = 0$, $I_{D} = 100 \mu A$
$V_{GS(OFF)}$			0.15		2	٧	$V_{DS} = 10V, I_D = 0.1 \mu A$
	Drain to Source Saturation Current	LSK389A	2.6		6.5	mA	V _{DS} = 10V, V _{GS} = 0
I_{DSS}		LSK389B	6		12		
		LSK389C	10		20		
I _{GSS}	Gate to Source Leakage Current				200	pА	$V_{GS} = -30V, V_{DS} = 0$

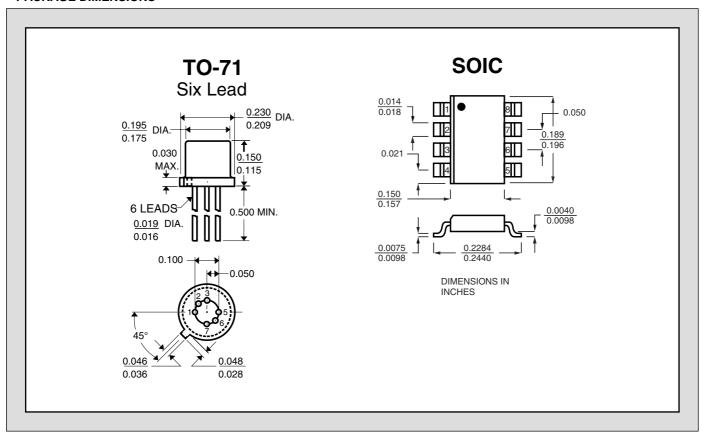
ELECTRICAL CHARACTERISTICS CONT. @ 25 °C (unless otherwise stated)

SYMBOL	CHARACTERISTIC	MIN	TYP	MAX	UNITS	CONDITIONS
Y _{fs}	Full Conduction Transconductance	8	20		mS	V_{DS} = 10V, V_{GS} = 0, I_{DSS} = 3mA, f = 1kHz
e _n	Noise Voltage		0.9	1.9	nV/√Hz	V_{DS} = 10V, I_{D} = 2mA, f = 1kHz, NBW = 1Hz
e _n	Noise Voltage		2.5	4	nV/√Hz	V_{DS} = 10V, I_{D} = 2mA, f = 10Hz, NBW = 1Hz
C _{ISS}	Common Source Input Capacitance		25		pF	$V_{DS} = 10V, V_{GS} = 0, f = 1MHz,$
C _{RSS}	Common Source Reverse Transfer Cap.		5.5		pF	$V_{DG} = 10V$, $I_{D} = 0$, $f = 1MHz$,

ORDERING INFORMATION



PACKAGE DIMENSIONS



Absolute maximum ratings are limiting values above which serviceability may be impaired.

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